# UNISONIC TECHNOLOGIES CO., LTD

# UTG75N65ND-S

**Preliminary** 

Insulated Gate Bipolar Transistor

# 650V TRENCH GATE FIELD-STOP IGBT

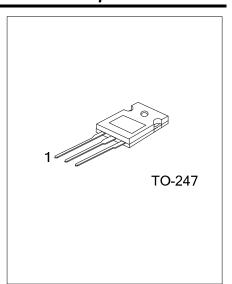
#### ■ DESCRIPTION

The UTC **UTG75N65ND-S** is an Trench Field-Stop Insulated Gate Bipolar Transistor. it uses UTC's advanced technology to provide customers with high switching speed, low saturation voltage and low switching loss, etc.

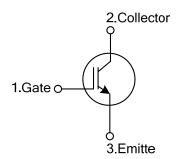
The UTC  ${\it UTG75N65ND-S}$  is suitable for the resonant or soft switching applications.

#### **■ FEATURES**

- \* High switching speed
- \* High avalanche ruggedness
- \* Low saturation voltage:  $V_{CE(SAT).Typ.}$ =1.65V @ I<sub>C</sub>=75A,  $V_{GE}$ =15V (T<sub>C</sub> =25°C)



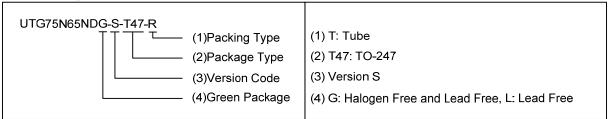
#### ■ SYMBOL



#### ■ ORDERING INFORMATION

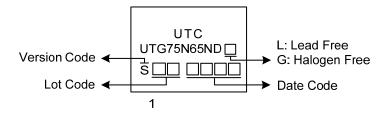
Ordering Number		Daalaana	Pin Assignment			Da alsisas	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UTG75N65NDL-S-T47-R	UTG75N65NDG-S-T47-R	TO-247	G	С	Е	Tape Reel	

Note: Pin Assignment: G: Gate C: Collector E: Emitter



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## **■** MARKING



### ■ ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	V <sub>CES</sub>	650	V
Gate-Emitter Voltage	\/	±20	V
Transient Gate-emitter voltage (tp < 5 ms)	$V_{GES}$	±25	V
Continuous Collector Current	Ic	150	Α
T <sub>C</sub> =100°C		75	Α
Collector Current Pulsed (Note 1)	Ісм	300	Α
Short Circuit Withstand Time	tsc		μs
V <sub>GE</sub> = 15V, V <sub>CC</sub> ≤ 200V			
Allowed number of short circuits < 1000		3	
Time between short circuits: ≥1.0s			
T <sub>VJ</sub> = 25°C			
Power Dissipation (T <sub>C</sub> =25°C)	P <sub>D</sub>	310	W
Operating Junction Temperature	TJ	-40 ~ +150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Absolute maximum ratings are those values beyond which the device could be permanently damaged.

#### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θις	0.4	°C/W

### ■ **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub>=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Off Characteristics							
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>			650			V
Collector Cut-Off Current	Ices	V <sub>CE</sub> =650V, V <sub>GE</sub> =0V				5	μΑ
G-E Leakage Current	I <sub>GES</sub>	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V				±400	nA
On Characteristics							
Gate to Emitter Threshold Voltage	$V_{GE(TH)}$	I <sub>C</sub> =250μA, V <sub>CE</sub> =V <sub>GE</sub>		4.5		6.5	V
Collector to Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =75A, V <sub>GE</sub> =15V	T <sub>C</sub> =25°C		1.65	2.1	V
			T <sub>C</sub> =125°C		2.0		V
Dynamic Characteristics							
Input Capacitance	CIES	V <sub>CE</sub> =25V, V <sub>GE</sub> =0V, f=1MHz			4740		pF
Output Capacitance	C <sub>OES</sub>				338		pF
Reverse Transfer Capacitance	C <sub>RES</sub>				67.7		pF
Switching Characteristics							
Total Gate Charge	$Q_G$				194.5		nC
Gate-Emitter Charge	$Q_GE$	V <sub>CE</sub> =520V, I <sub>C</sub> =75A, V <sub>GE</sub> =15V			41.3		nC
Gate-Collector Charge	$Q_GC$			98.6		nC	
Turn-On Delay Time	t <sub>DON)</sub>				11.8		ns
Rise Time	t <sub>R</sub>	V <sub>CC</sub> =400V, I <sub>C</sub> =75A, R <sub>G</sub> =10Ω, V <sub>GE</sub> =0~15V, L=100uH			22		ns
Turn-Off Delay Time	t <sub>DOFF)</sub>				52.9		ns
Fall Time	t <sub>F</sub>				174		ns
Turn-On Switching Loss	Eon				0.881		mJ
Turn-Off Switching Loss	E <sub>OFF</sub>			0.724		mJ	

<sup>2.</sup> Pulse width limited by maximum junction temperature.

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